

# KOI-6001B

## Features

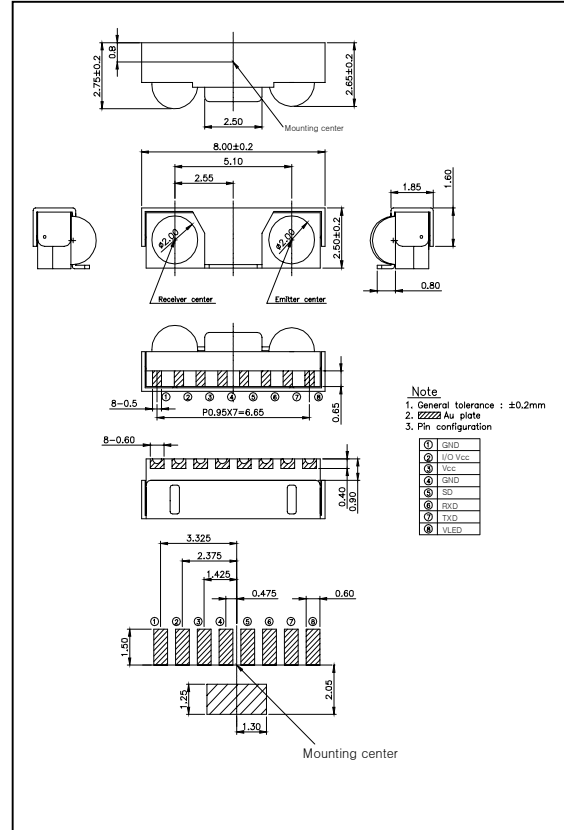
- Compliant to IrDA 1.4 Low Power Standard
- Wide Voltage Operation : 2.7 ~ 5.5V
- Compact Package Integrated Transmitter and Receiver (8.0L x 2.75W x 2.5T)
- Complete Power Down Mode for the Current Consumption.
- No LED bias resistor needed
- Shielded Package for Preventing EMI
- LED Stuck-high Protection
- Lead-free & High reliability package

## Applications

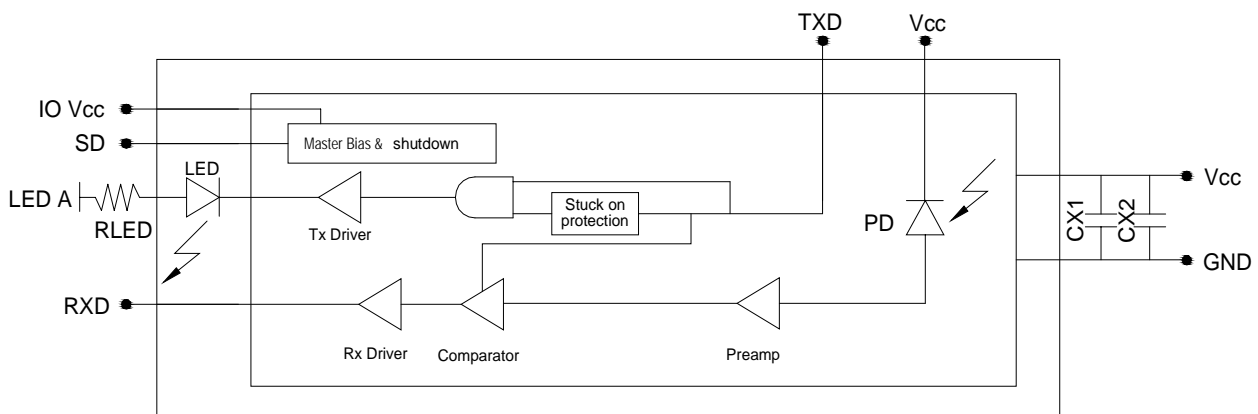
- Cellular Phone
- Personal Computer(Desk-top PC, Lap-top PC)
- Printers, Vending Machine, ATM
- Personal Digital Assistants.(PDA)

## Dimensions

(Unit : mm)



## Block Diagram



RLED 4.7Ω±5%, 0.25 Watt, Vcc=2.7~4.2V  
 CX1 0.47μF±20%, Ceramic  
 CX2 4.7μF±20%, Tantalum  
 CX1, CX2 must be placed 7mm of the KOI-6001B

**KOI-6001B**

**Absolute Maximum Ratings**

[Ta = 25 °C ]

Parameter	Symbol	Conditions	Min.	Max.	Unit
Supply Voltage	V <sub>CC</sub>	-	0	6.5	V
LED Supply Voltage	V <sub>LED</sub>	-	0	6.0	V
Operating Temperature	T <sub>opr.</sub>	-	-20	85	°C
Storage Temperature	T <sub>stg.</sub>	-	-40	100	°C
DC LED Transmit Current	I <sub>LED (DC)</sub>	-	-	50	mA
Peak LED Transmit Current	I <sub>LED (PK)</sub>	<90µs pulse width, <20% duty cycle	-	200	mA
Receiver Data Output Voltage	V <sub>RxD</sub>	-	-0.5	V <sub>CC</sub> +0.5	V
Transmitter Data Input Voltage	V <sub>TxD</sub>	-	-0.5	V <sub>CC</sub> +0.5	V
Data Rate	BR	-	9.6	115.2	kbit/s

**4. Electro-Optical Characteristics**

[Ta=25°C , V<sub>CC</sub>=3.3V]

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
Supply Current	I <sub>cc1</sub>	Shutdown	-	-	1	µA	
	I <sub>cc2</sub>	Idle	-	100	200	µA	
Transmitter	Transmitter Wakeup Time	T <sub>tw</sub>	-	20	50	µs	
	Viewing Angle	2θ <sub>1/2</sub>	30	-	60	deg.	
	Data Output Pulse Width	T <sub>stp</sub> w	tpw(RxD)=1.63µs at 115.2kbit/s	1.6	1.7	1.9	µs
	Rise Time	t <sub>r</sub>	BR=115.2kbit/s	-	50	600	ns
	Fall Time	t <sub>f</sub>		-	50	600	ns
	Peak Emission Wavelength	λ <sub>p</sub>	-	-	875	-	nm
	Spectral Bandwidth	Δλ	-	-	45	-	nm
Receiver	Viewing Angle	2θ <sub>1/2</sub>	30	-	-	deg.	
	Peak Sensitivity Wavelength	λ <sub>p</sub>	-	880	-	nm	
	High Level Output Voltage	V <sub>OH</sub>	I <sub>OH</sub> =-20µA	V <sub>CC</sub> -0.2	-	-	V
	Low Level Output Voltage	V <sub>OL</sub>	I <sub>OL</sub> =1mA	-	-	0.4	V
	Rx SIR Pulse Width	T <sub>srp</sub> w	tpw(RxD)=1.63µs at 115.2kbit/s	1	1.2	4	µs
	Rise Time	t <sub>r</sub>	BR=115.2kbit/s	-	50	600	ns
	Fall Time	t <sub>f</sub>		-	50	600	ns
	Communication Distance	D		20	60	-	cm
	Receiver Latency Time	TL		-	40	80	µs
Receiver Wakeup Time	T <sub>rw</sub>		-	60	120	µs	